

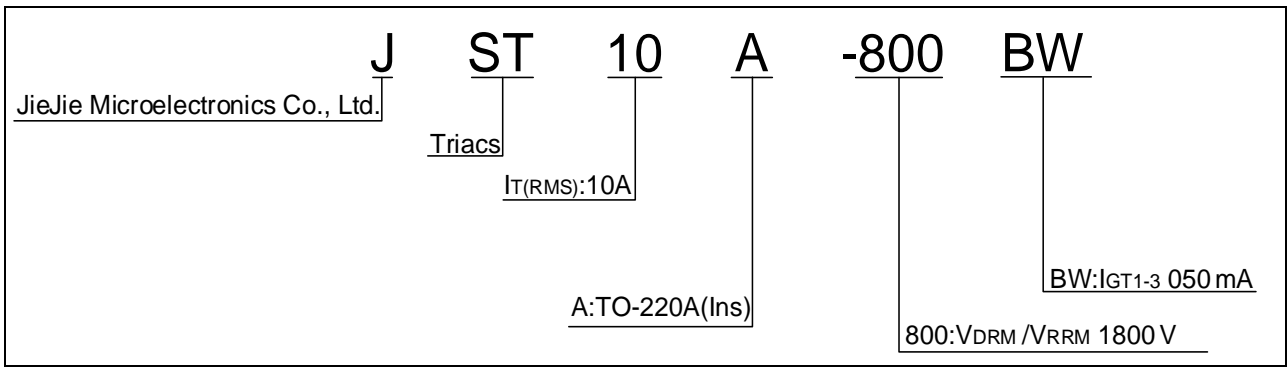


Peak gate power	$P_{GM}$	10	W
Peak pulse voltage ( $T_j=25$ ; non-repetitive, off-state; FIG.7)	$V_{pp}$	4.5	kV

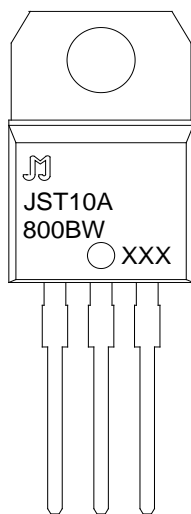
**ELECTRICAL CHARACTERISTICS** (unless otherwise specified)

Symbol	Test Condition	Quadrant	Value	Unit
$I_{GT}$	$V_D=12V$ $R_L=33$	-		

ORDERING INFORMATION



MARKING







## ORDERING INFORMATION

Order code	Voltage $V_{DRM}/V_{RRM}$ (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
		H- I- J			
JST10A-800BW	800	50	TO-220A(Ins)	50	Tube

## Document Revision History

Date	Revision	Changes
Apr.11, 2023	A.1.0	Last updated



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